Scaling Behavior of the First Arrival Time of a Random-Walking Magnetic Domain

M.-Y. Im, 1,2 S.-H. Lee, D.-H. Kim, P. Fischer, and S.-C. Shin

¹Department of Physics and Center for Nanospinics of Spintronic Materials, Korea Advanced Institute of Science and Technology, Daejeon 305-701, Korea

²Center for X-ray Optics, Lawrence Berkeley National Laboratory, Berkeley, California 94720, USA

³Department of Physics, Chungbuk National University, Chungbuk 361-763, Korea

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We report a universal scaling behavior of the first arrival time of a traveling magnetic domain wall into a finite space-time observation window of a magneto-optical microscope enabling direct visualization of a Barkhausen avalanche in real time. The first arrival time of the traveling magnetic domain wall exhibits a nontrivial fluctuation and its statistical distribution is described by universal power-law scaling with scaling exponents of 1.34 ± 0.07 for CoCr and CoCrPt films, despite their quite different domain evolution patterns. Numerical simulation of the first arrival time with an assumption that the magnetic domain wall traveled as a random walker well matches our experimentally observed scaling behavior, providing an experimental support for the random-walking model of traveling magnetic domain walls.

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The statistical distribution of the arrival time into finite area in seemingly random dynamical systems has been extensively investigated in a wide variety of physical systems, such as queuing of server jobs, earthquakes, epidemic, ocean waves, and heavy vehicle traffic [1–7]. Magnetization reversal under an external magnetic field has been considered to be a very good example of a system with complex dynamics, exhibiting nontrivial fluctuations leading to scaling behavior, ever since the almost centuryold discovery of the Barkhausen avalanche [8–10]. Most statistical studies on magnetic reversal phenomena have been concentrated to examine fluctuating quantities such as the size of a Barkhausen jump, which exhibits scaling behavior described by a power-law distribution of the fluctuating quantity [8–11]. However, a long-standing unsolved issue is the statistical behavior of the first arrival time of a traveling magnetic domain wall, which presumably undergoes a chain of avalanche events until it finally enters the finite space-time observation window. But, there has been no experimental study devoted to the statistical behavior of first arrival times of a traveling magnetic domain wall during a Barkhausen avalanche in ferromagnetic films.

Traveling domain-wall motion during a Barkhausen avalanche has long been predicted to have a random-walking behavior [12–14]. It is believed that pinning sites with a Gaussian spatial distribution provide a playground for the random-walking magnetic domain wall. Much effort has been devoted to understanding the Barkhausen avalanche, for example, based on the Langevin equation [15] with a Brownian-motion-like randomly fluctuating force. Recently, great attention has been paid to the scaling behavior of random-walking statistics [16–19], with various scaling exponents theoretically predicted depending on the details of the random-walking method. So far, very little connection has been made between the theoretically

predicted random-walk behavior of a Barkhausen avalanche and experimentally observed fluctuating magnetic domain walls. Thus, providing clear experimental evidence for the random-walking magnetic domain-wall model and for the scaling behavior of magnetic domain dynamics remains a scientific challenge to date.

In this Letter we have investigated the statistical distribution of the first arrival time of a traveling magnetic domain wall into an observation area during a Barkhausen avalanche. The samples used in our study were nanogranular CoCr and CoCrPt alloy films, which show quite different domain evolution patterns even for small additions of Pt [20].

The magnetic domain walls were triggered by applying an external magnetic field near the coercive field strength, to 1 cm × 1 cm CoCr and CoCrPt alloy films. The distribution of the first arrival times of the domain walls into the $40 \mu m \times 32 \mu m$ observation area was measured using thousands of time-resolved domain evolution patterns with observation time windows of 1, 30, and 60 seconds. Direct observation of time-resolved magnetic domain patterns was carried out using a magneto-optical microscope magnetometer (MOMM) [21]. The MOMM system basically consists of a polarizing optical microscope designed to observe in-plane magnetic domains via the longitudinal magnetic-optical Kerr effect. The spatial and Kerr angle resolution were 400 nm and 0.1°. A series of 128 domain evolution patterns was captured in real time. 10-nm thick Co₈₂Cr₁₈ and (Co₈₂Cr₁₈)₉₇Pt₃ alloy films were prepared on glass substrates at an ambient temperature using dc magnetron cosputtering of a CoCr alloy target and a Pt target at a base pressure of 8×10^{-7} Torr and an Ar sputtering pressure of 3 mTorr. The compositions of the alloy samples were confirmed by energy dispersive x-ray spectroscopy. The magnetic easy axis determined using a torque magnetometer was found to be in the plane for all samples.

Figure 1(a) shows the time-resolved domain evolution patterns of the CoCr alloy film obtained from five consecutive experiments using the MOMM system, together with time-dependent magnetization reversal curves corresponding to the domain evolution patterns. The color coding from red to blue indicates an elapsed time between 0 to 1 s. The discrete and random Barkhausen avalanches are clearly visible as shown in each row in Fig. 1(a). We specify the time when the Barkhausen jump was observed in the upper left corner of each picture. The images were obtained successively from the same 40 μ m \times 32 μ m area of film under a constant reversing magnetic field with strength about 99% of the coercivity, $H_c \approx 85$ Oe. Interestingly, one clearly sees in Fig. 1(a) that the first arrival time of the magnetic domain wall into the finite observation window is quite different for successive mea-

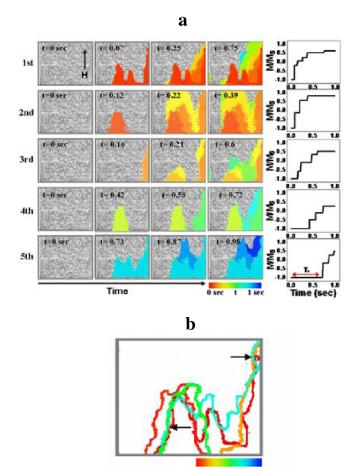


FIG. 1 (color online). (a) Time-resolved domain evolution patterns and corresponding time-dependent magnetization reversal curves taken from five consecutive experiments at the same sample area (40 μ m \times 32 μ m) of Co₈₂Cr₁₈ alloy film. The color code represents the elapsed time from 0 to 1 sec. (b) Superimposed image of first-arriving magnetic domain walls, where the colors of domain walls correspond to the elapsed time represented by the color palette in the figure.

surements although the observations were carried out under identical experimental conditions.

The difference in the first arrival time of the magnetic domain wall can also be clearly seen in the time-dependent magnetization reversal curves. The magnetization curves were determined by analyzing the time-resolved domain images. The magnetization of each magnetic domain was either parallel or antiparallel to the applied magnetic field direction, which could be seen by two clear levels of magnetic contrast for all the samples. The magnetization curve was thus determined by quantitatively analyzing the magnetic domain area of each image, neglecting magnetization variation perpendicular to the plane of the film. The magnetization curve with sudden changes of magnetization is typical of the nature of a Barkhausen avalanche. The first arrival time of the magnetic domain wall into the observation area of the MOMM system is denoted as T_0 and the measured value of T_0 for each experiment is indicated in the second column of Fig. 1(a). It shows that T_0 fluctuates for each successive measurement even under the same experimental conditions. Considering the fact that the CoCr alloy film with the grain size of \sim 20 nm provides numerous pinning sites, probably at grain boundaries mainly due to the Cr compositional segregation [20,22], one can hypothesize that the magnetic domain walls jump around among these pinning sites, generating the Barkhausen avalanches, and finally arrive into the experimental observation area with a different first arrival time for each observation. To verify this hypothesis, the images of the first-arriving magnetic domain walls are compared. In Fig. 1(b), several images of the first-arriving domain walls are superimposed in one picture. Although the overall domain shapes are always spikelike, there are only a few common positions where the first-arriving domain walls are repeatedly found. These common positions are probably due to the existence of strong local pinning sites as indicated by the arrows.

To systematically investigate the statistical nature of T_0 , the experiments have been repeated more than 1000 times at each observation area and on various areas of Co₈₂Cr₁₈ and $(Co_{82}Cr_{18})_{97}Pt_3$ films, respectively. Three different time windows of 1, 30, and 60 sec have been used and the distribution of T_0 is plotted on a log-log scale in Fig. 2. The distributions of T_0 were determined under the field strength about 99% of the coercivity, $H_c \approx 85$ Oe and $H_c \approx 92$ Oe for $Co_{82}Cr_{18}$ and $(Co_{82}Cr_{18})_{97}Pt_3$ films, respectively. The insets of the figures are a typical example of time-resolved domain evolution pattern of the CoCr and CoCrPt films. The (Co₈₂Cr₁₈)₉₇Pt₃ film has a much simpler stripelike domain-wall evolution pattern, compared to the spikelike one observed in the Co₈₂Cr₁₈ film. It has been predicted that only 3% addition of Pt in atomic composition could significantly reduce the number of defects and hence simplifying the domain shapes [20]. The first arrival time T_0 of the traveling magnetic domain wall in a

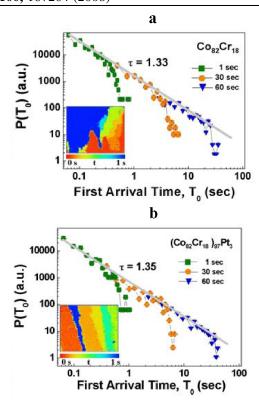


FIG. 2 (color online). Distributions of the first arrival time of a magnetic domain wall in (a) $Co_{82}Cr_{18}$ and (b) $(Co_{82}Cr_{18})_{97}Pt_3$ alloy films determined from the statistical analysis of the fluctuating first arrival time. Best fitting curves determined by the least mean square method are shown in the figures.

Barkhausen avalanche shows a nontrivial fluctuation and distributions of T_0 taken at observation time windows of 1, 30, and 60 sec in CoCr and CoCrPt alloy films can be described by a power-law scaling distribution $P(T_0)$ ~ $(T_0)^{-\tau}$ with $\tau = 1.33 \pm 0.06$, and $\tau = 1.35 \pm 0.04$, respectively. The scaling exponents are found to be the same within the measurement error independent of the length of the observation time window. The exponent value of about 1.33 obtained in CoCr sample was found to be same with variation in an applied magnetic field strength ranging from 0.97 H_c to 0.997 H_c . Therefore, the scaling behavior of the first arrival time of a magnetic domain wall is believed to be invariant with variation in an applied magnetic field. It should be pointed out that the experimentally determined values of the scaling exponents for the CoCr and CoCrPt alloy films are nearly the same within the experimental error despite their quite different domain evolution patterns. In Fig. 2, note that the cutoff of the power-law scaling exists near the upper boundary of each time window, probably due to the finite size effect of the observation area [11].

To theoretically investigate the scaling behavior of the first arrival time of a magnetic domain wall, we consider a random walk as an analogy to the moving domain wall based on numerous theoretical studies over the past decades that a domain wall behaves like a random-walking single particle [13–15]. In our simulation, we have applied the simple model of an unbiased 2D random-walker to both CoCr alloy and CoCrPt alloy films, because the domain-walls propagate in a wide range of the orientations with the repetitive measurements, without any preferential direction of domain-wall motion. This result is believed to ascribe to the fact that the film has no uniaxial magnetic anisotropy in the easy plane of the film and isotropic distribution of pinning sites. Hence, it is reasonable to adopt an unbiased 2D model rather than a biased 2D model or a 1D model. It should be mentioned that a biased 2D or a 1D random-walker model could not predict a power-law behavior.

Simulations have been carried out to determine the first arrival time of an unbiased random-walker in two dimensions with a Gaussian-distributed step length with mean values $\mu = 1, 2, 4$ and standard deviations $\sigma = 1, 2, 3$. The step length of the random-walker can be considered as the distance between two successive pinning sites. We found that our random-walk simulation code produces a scaling behavior of $\langle R_N^2 \rangle \sim N^{2\nu}$ with a typical scaling exponent $\nu = 0.5$, where R_N is the displacement of the random-walker from the starting point after N steps. The value of the scaling exponent $\nu = 0.5$ has been reported in numerous studies [23,24]. In this simulation, 10 random walkers were generated in the area of 2000×2000 cells. The observation area of 20×20 cells was set with consideration of the ratio between the sample size $(1 \text{ cm} \times 1 \text{ cm})$ of the CoCr and CoCrPt films and the observation window size (40 μ m × 32 μ m) of the MOMM. The initial position of each random-walker was randomly chosen but constrained to be outside the observation area. The direction of the random walk step in two dimensions was random without any preferred direction. The randomwalking process was iterated until one of the 10 randomwalkers entered the observation area. Thus, the number of steps during this process corresponds to the first arrival time of the magnetic domain wall.

The statistical distribution of the first arrival time was determined by running more than 50 000 simulations for each choice of μ and σ , as shown in Fig. 3. The Gaussian distribution functions used in our simulations are inserted in the figures. One clearly sees that the first arrival time of the random-walker in all cases displays a power-law scaling distribution, in agreement with the experimental results for the first arrival time of a traveling magnetic domain wall. Furthermore, the scaling exponent determined from our simulation, considered to be the most important parameter in the description of this nontrivial fluctuation phenomenon, is found to be the same with a value of 1.35 ± 0.06 for all configurations irrespective of the values of μ and σ . Our simulation results seem to be very well matched to the experimental ones within the errors, which answers the historical question of whether a traveling magnetic domain wall can be described by a random walk.

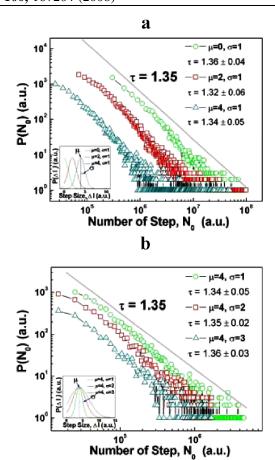


FIG. 3 (color online). Distributions of the first arrival time of a random walker obtained from numerical simulations with varying (a) mean values ($\mu = 1, 2, 4$) and (b) standard deviations ($\sigma = 1, 2, 3$) of the Gaussian-distributed random-walk step size. Best fitting curves are displayed in the figures.

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